April 2007

FAIRCHILD

SEMICONDUCTOR

FFPF10H60S Hyperfast 2 Rectifier

Features

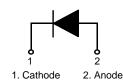
- + High Speed Switching ($t_{\rm rr}{=}25ns(Typ.) @ I_{\rm F}{=}10A$)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- + Low Forward Voltage($V_F\!\!=\!\!2.1V(Typ.)$ @ $I_F\!\!=\!\!10A$)

Applications

- General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits

Pin Assignments





10A, 600V Hyperfast 2 Rectifier

struction.

tors.

The FFPF10H60S is hyperfast2 rectifier (t_{rr} =25ns(Typ.) @ I_{F} =10A). it has half the recovery time of ultrafast rectifier and is

silicon nitride passivated ion-implanted epitaxial planar con-

This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power swithching applications. Its low stored charge and hyperfast soft

recovery minimize ringing and electrical noise in many power

switching circuits reducing power loss in the switching transis-

1. Cathode 2. Anode

Absolute Maximum Ratings $T_{c} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ $T_C = 85 \ ^{\circ}C$	10	А	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	100	A	
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C	

Thermal Characteristics T_c = 25°C unless otherwise noted

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.4	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F10H60S	FFPF10H60STU	TO-220F	-	-	50

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FFPF10H60S Hyperfast 2 Rectifier

Parameter	Conditions			Тур.	Max	Units
V _{FM} ¹	I _F = 10A I _F = 10A	T _C = 25 °C T _C = 125 °C	-	2.1 -	2.5 2.2	V V
I _{RM} ¹	$V_{R} = 600V$ $V_{R} = 600V$	T _C = 25 °C T _C = 125 °C	-	-	1 2	mA mA
t _{rr}	$\begin{split} I_{F} = & 1A, \ di/dt = 100A/\mu s, \ V_{CC} = 30V \\ I_{F} = & 10A, \ di/dt = 50A/\mu s, \ V_{CC} = 390V \\ I_{F} = & 10A, \ di/dt = 200A/\mu s, \ V_{CC} = 390V \end{split}$	$T_{C} = 25 \text{ °C}$	- -	- 25 21	35 40 -	ns ns ns
t _a t _b Q _{rr}	I_F =10A, di/dt = 50A/µs, V _{CC} = 390V	$T_{C} = 25 °C$ $T_{C} = 25 °C$ $T_{C} = 25 °C$ $T_{C} = 25 °C$	- -	15 10 9.0		ns ns nC
W _{AVL}	Avalanche Energy (L = 40mH)		20	-	-	mJ

dlF

đt

VAVL

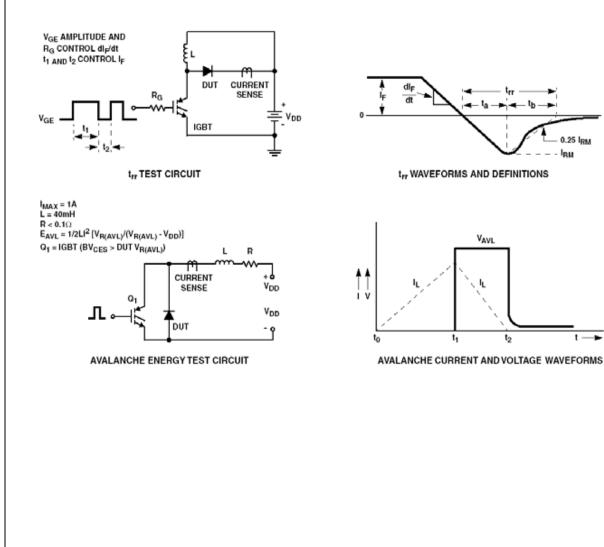
t₁

t₂

Notes:

1. Pulse : Test Pulse width = 300μ s, Duty Cycle = 2%

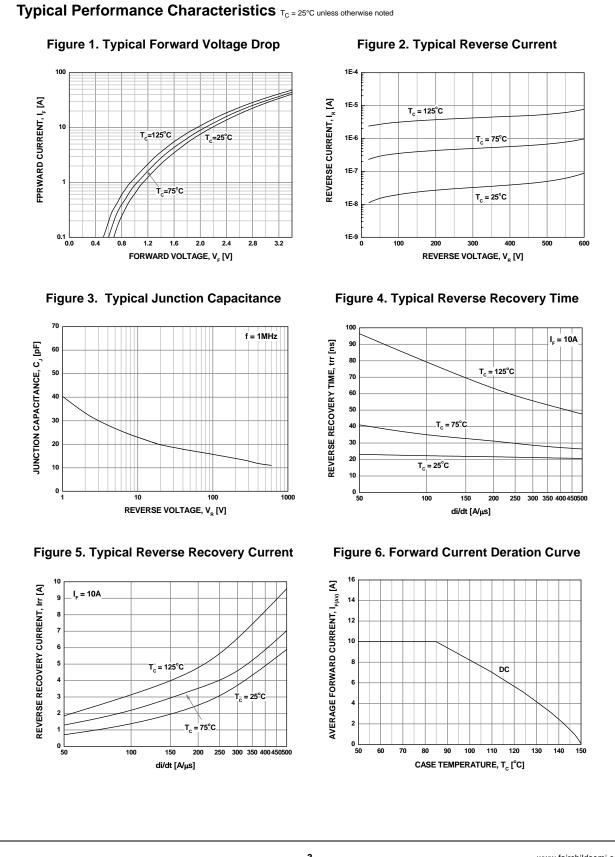
Test Circuit and Waveforms



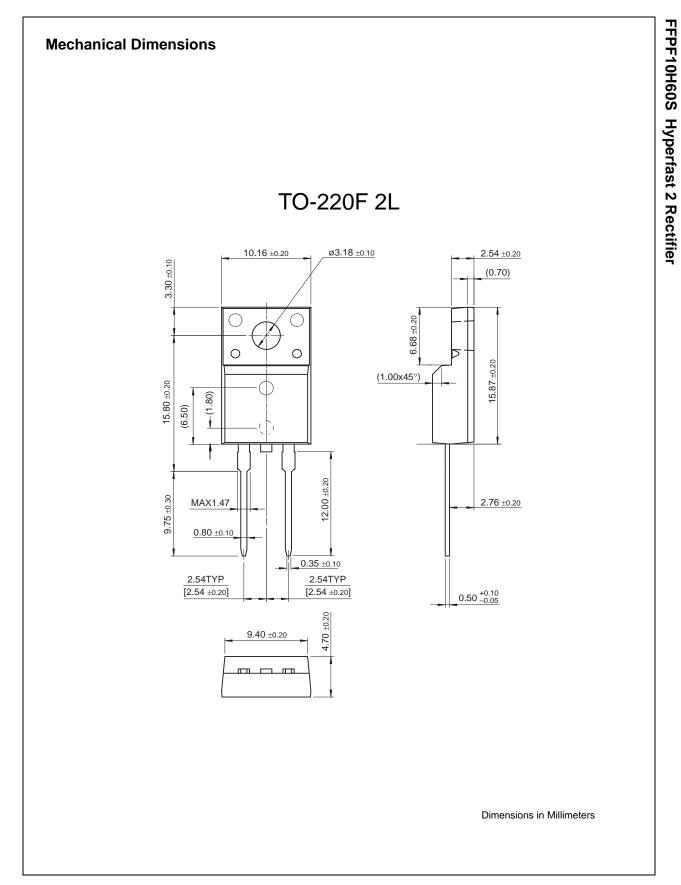
0.25 I_{RM} IRM

t

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FFPF10H60S Rev. A



FFPF10H60S Rev. A



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Build it Now™	ImpliedDisconnect [™]	Programmable Active Droop™	U.
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FRFET [®]	Power220 [®]	SuperSOT™-8	

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